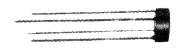


1W005 THRU 1W10

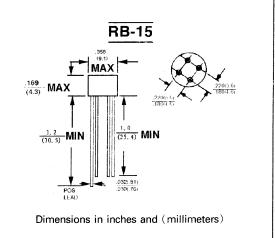
SINGLE PHASE 1.0 AMP SILICON BRIDGE RECTIFIERS



FEATURES

- * Ideal for printed circuit board
- * High Surge Current Capability
- * Reliable low cost construction technique results in inexpensive product

VOLTAGE RANGE 50 to 1000 Volts CURRENT 1.0 Ampere



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%

TYPE NUMBER	SYMBOLS	1 W 005	1 W 01	1 W 02	1 W 04	1 W 06	1 W 08	1 W 10	UNITS
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Bridge Input Voltage	V _{RMS}	35	70	140	280	420	560	700	٧
Maximum D.C Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current @ T _A = 60°C	l _{F(AV)}	1.0						Α	
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposedon rated load(JEDEC method)	I _{FSM}	30						Α	
Maximum Forward Voltage Drop per element @ 1.0A	V _F	1.10						٧	
Maximum Reverse Current at Rated @ $T_A = 25^{\circ}C$ D. C. Blocking Voltage per element @ $T_A = 100^{\circ}C$	l _R	10 500						μ Α μ Α	
Operating Temperature Range	TJ	– 55 to + 125							℃
Storage Temperature Range	T _{STG}	– 55 to + 150							℃



RATINGS AND CHARACTERISTIC CURVES (1W005 THRU 1W10)

FIG. 1-MAXIMUM NON - REPETITIVE PEAK FORWARD SURGE CURRENT - PER ELEMENT

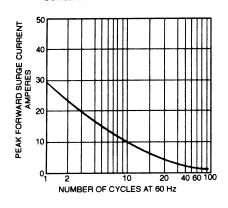


FIG. 2-TYPICAL FORWARD OUTPUT CURRENT DERATING CURVE

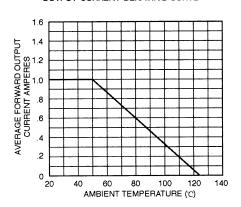


FIG. 3-TYPICAL FORWARD CHARACTERISTICS PER ELEMENT

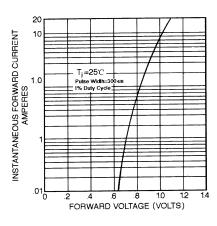


FIG. 4-TYPICAL REVERSE CHARACTERISTICS PER ELEMENT

